

IN THE TITLE

Please delete the title in its entirety and insert — A DEVICE WITH
RECESSED THIN AND THICK SPACERS FOR IMPROVED SALICIDE
RESISTANCE ON POLYSILICON GATES — therein.

IN THE SPECIFICATION

Please insert as a separate paragraph below the title on page 1 – This is a
division of Application No. 09/386,495, filed August 30, 1999, which is a further
division of Application No. 09/191,729, filed November 13, 1998. – therein.

IN THE CLAIMS

Please enter the following claims:

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31. (Once Amended) A gate electrode comprising:
- an insulative layer disposed on a substrate;
 - a gate layer disposed on said insulative layer;
 - a conductive layer disposed on said gate layer, said conductive layer
extending beyond edges of said gate layer;
 - thin first spacers disposed adjacent to opposite sides of said gate layer
wherein said thin first spacers are recessed to lower surface of said conductive layer;

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